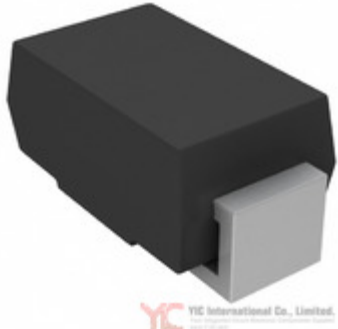
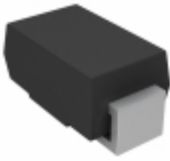
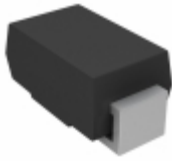
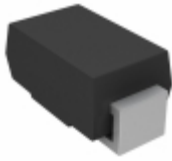


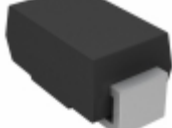
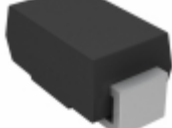

	<h2>S1JHE3/5AT</h2>
	<p>Hersteller-Teilenummer: S1JHE3/5AT</p> <p>Hersteller / Marke: Vishay / Semiconductor - Diodes Division</p> <p>Teil der Beschreibung: DIODE GEN PURP 600V 1A DO214AC</p> <p>Datenblätter: 1.S1JHE3/5AT.pdf 2.S1JHE3/5AT.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 79160 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	S1JHE3/5AT
Hersteller	Vishay / Semiconductor - Diodes Division
Beschreibung	DIODE GEN PURP 600V 1A DO214AC
Kategorie	Diskrete Halbleiterprodukte > Dioden-Gleichrichter-
Teilstatus	79160 pcs Stock
Serie	-
Befestigungsart	Surface Mount
Verpackung / Gehäuse	DO-214AC, SMA
Supplier Device-Gehäuse	DO-214AC (SMA)
Diodentyp	Standard
Strom - Richt (Io)	1A
Spannung - Forward (Vf) (Max) @ If	1.1V @ 1A
Strom - Sperrleckstrom @ Vr	1µA @ 600V
Spannung - Sperr (Vr) (max)	600V
Geschwindigkeit	Standard Recovery >500ns, > 200mA (Io)
Rückwärts-Erholzeit (Trr)	1.8µs
Betriebstemperatur - Anschluss	-55°C ~ 150°C
Kapazität @ Vr, F	12pF @ 4V, 1MHz
Verpackung	Tape & Reel (TR)

S1JHE3/5AT ist neu im Original, Suche S1JHE3/5AT Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie S1JHE3/5AT Vishay / Semiconductor - Diodes Division mit Garantie und Vertrauen. Anfrage S1JHE3/5AT: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>S1JHE3_A/H Electro-Films (EFI) / Vishay DIODE GEN PURP 600V 1A DO214AC</p>	 <p>S1JHE3_A/H Vishay / Semiconductor - Diodes Division DIODE GEN PURP 600V 1A DO214AC</p>	 <p>S1JHE3/61T Vishay / Semiconductor - Diodes Division DIODE GEN PURP 600V 1A DO214AC</p>	 <p>S1JHE AMI Semiconductor / ON Semiconductor DIODE GEN PURP 600V 1A SOD323HE</p>
 <p>S1JFSHMxG TSC (Taiwan Semiconductor) DIODE, 1A, 600V, AEC-Q101, SOD-1</p>	 <p>S1JHE3/61T Electro-Films (EFI) / Vishay DIODE GEN PURP 600V 1A DO214AC</p>	 <p>S1JHE3/5AT Electro-Films (EFI) / Vishay DIODE GEN PURP 600V 1A DO214AC</p>	 <p>S1JHE Fairchild/ON Semiconductor DIODE GEN PURP 600V 1A SOD323HE</p>

heiße Teile

Mehr

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D LTC485CN8#PBF	MAX6717UKSDD3-T	MC34933EPR2	MMBT4401LT1G	MRFIC0917R2
PH6030DLV	PH7030DL	RB520G30	S1J-004HE3/5AT	S1J-13-F
S1J-13-G-72	S1J-6605E3/11	D S1J-6605HE3/61T	S1J-6906/11T	S1J-6906E3/61T
S1J-6906HE3/61T	D S1J-E3/11T	S1J-E3/5AT	S1J-E3/5AT	S1J-E3/61T
S1J-E3/61T	S1J-M3/61T	S1J-M3/61T	S1JA-E3/61T	S1JA-E3/61T
S1JB-13-F	S1JHE3/5AT	S1JHE3/61T	D S1JHE3/61T	S1JHE3_A/I
S1JHE3_A/I	SD300N28MBC	SG30TC10M	SKKH203/12E	VI-JT0-IZ

Contact us: Info@Y-IC.com

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